TOSHIBA TA8164P

TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

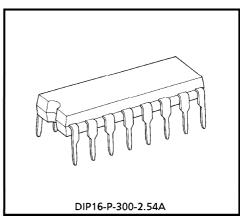
TA8164P

3V MONAURAL RADIO IC

The TA8164P is AM/FM Tuner (FM F/E+AM/FM IF) IC, which is designed for AM/FM monaural radio. Combining with the TA7368P (Mono PW IC), a suitable monaural AM/FM radio system is able to be constituted.

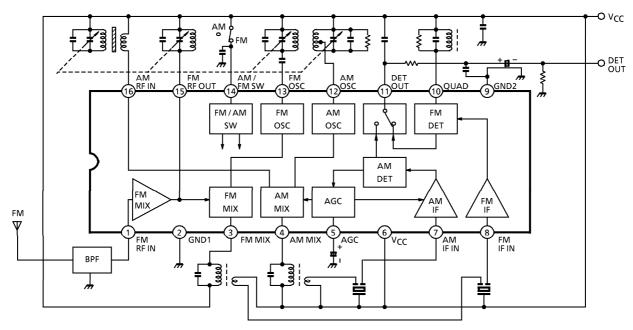
FEATURES

- Common output for AM/FM
- Switch over between AM/FM mode is possible with onewake switch.
- Operating supply voltage range : $V_{CC(opr)} = 1.8 \sim 7V \text{ (Ta} = 25^{\circ}\text{C)}$



Weight: 1.00g (Typ.)

BLOCK DIAGRAM



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EXPLANATION OF TERMINAL

	ANATION OF TERMINAL		D6 1/0:-	TAGE 44	
PIN No.	SYMBOL	INTERNAL CIRCUIT	DC VOLTAGE (V) (AT NO SIGNAL)		
140.			AM	FM	
1	FM-RF IN	FM-RF OUT 13	0	0.7	
2	GND1 (GND for AM RF, OSC, MIX, FM RF, OSC, MIX)	_	0	0	
3	FM MIX	AM/FM SW 13	3.0	3.0	
4	AM MIX	VCC 6 MIX	3.0	3.0	
5	AGC (AM AGC)	IF AGC S RF AGC GND2 GND2 GND2 GND2 GND2 GND2 GND2 GND2 GND2 GND2 GND2 GND2 G	0	0	
6	Vcc	-	3.0	3.0	
7	AM IF IN	Vcc 6 G G G G G G G G G G G G G G G G G G	3.0	3.0	
8	FM IF IN	V _{CC} 6	3.0	3.0	

PIN	SYMBOL	INTERNAL CIRCUIT	DC VOLTAGE (V) (AT NO SIGNAL)		
No.			AM	FM	
9	GND2 (GND for AM IF and FM IF)	_	0	0	
10	QUAD (FM QUAD, Detector)	V _{CC} ©	3.0	3.0	
11	DET OUT	VCC 6 ® O B D B D B D B D D B D D D D D D D D D	1.4	1.4	
12	AM OSC	VCC 6 MIX	3.0	3.0	
13	FM OSC	AM/FM SW (1) (1) (3) (4) (5) (6) (7) (7) (7) (7) (8) (9) (1) (1) (1) (1) (1) (1) (1	3.0	3.0	
14	AM / FM SW PIN [®] V _{CC} → FM PIN [®] OPEN → AM	AM IF FM F/E C SO C C SO C SO C SO C SO C SO C SO C	_	3.0	
15	FM RF OUT	cf. pin①	3.0	3.0	
16	AM RF IN	VCC 6 16 GND1 2	3.0	3.0	

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	Vcc	8	V
Power Dissipation	P _D (Note)	750	mW
Operating Temperature	T _{opr}	- 25∼75	°C
Storage Temperature	T _{stg}	- 55∼150	°C

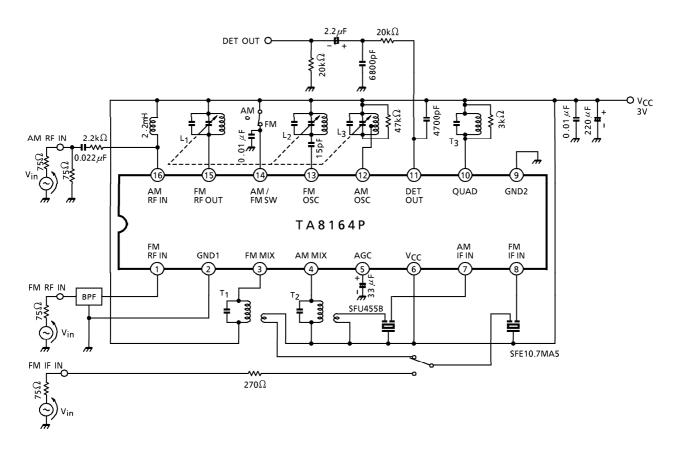
(Note) Derated above $Ta = 25^{\circ}C$ in the proportion of $6mW/^{\circ}C$.

ELECTRICAL CHARACTERISTICS

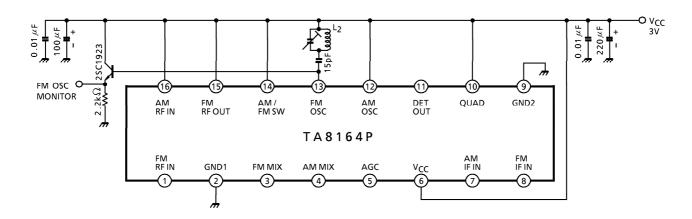
Unless otherwise specified, Ta = 25°C, V_{CC} = 3V, F/E : f = 98MHz, f_m = 1kHz FM IF : f = 10.7MHz, Δf = \pm 22.5kHz, f_m = 1kHz AM : f = 1MHz, MOD = 30%, f_m = 1kHz

				•					
CHARACTERISTIC		SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
Summits Comment		I _{CC} (FM)	1	FM Mode V _{in} = 0	_	10.5	15.5	0	
Supp	oly Current	ICC (AM)	1	AM Mode V _{in} = 0	_	4.5	7.0	mA	
	Input Limiting Voltage	V _{in} (lim)	1	-3dB limiting point	_	12	_	dBμV EMF	
FM F/E	Quiescent Sensitivity	QS	1	S / N = 30dB	_	12	_	dBμV EMF	
' -	Local OSC Voltage	Vosc	2	f _{OSC} = 108MHz	150	205	280	mV_{rms}	
	Local OSC Stop Supply Voltage	V _{stop} (FM)	2	V _{in} = 0	_	1.2	_	٧	
	Input Limiting Voltage	V _{in} (lim) IF	1	-3dB limiting point	44	50	56	dBμV EMF	
FM	Recovered Output Voltage	V _{OD}	1	V _{in} = 80dBμV EMF	20	35	55	mV _{rms}	
IF	Signal To Noise Ratio	S/N	1	$V_{in} = 80 dB \mu V EMF$	_	62	_	dB	
	Total Harmonic Distortion	THD	1	V _{in} = 80dBμV EMF	_	0.4	_	%	
	AM Rejection Ratio	AMR	1	$V_{in} = 80 dB \mu V EMF$	_	33	_	dB	
	Gain	Gγ	1	$V_{in} = 30 dB \mu V EMF$	15	30	45	mV_{rms}	
	Recovered Output Voltage	V _{OD}	1	$V_{in} = 60 dB \mu V EMF$	20	35	55	mV _{rms}	
AM	Signal To Noise Ratio	S/N	1	$V_{in} = 60 dB \mu V EMF$	_	43	_	dB	
	Total Harmonic Distortion	THD	1	V _{in} = 60dBμV EMF		1.0	_	%	
	Local OSC Stop Supply Voltage	V _{stop} (AM)	1	V _{in} = 0	_	1.6	_	٧	

TEST CIRCUIT 1



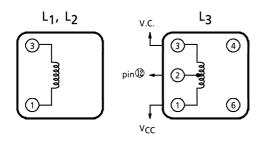
TEST CIRCUIT 2

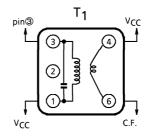


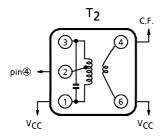
COIL DATA

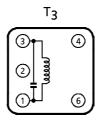
COIL No.	f	L	C _O (pF)	Qo	TURNS					WIRE	REF.	
COIL NO.	(Hz)	(μH)			1-2	2-3	1-3	1-4	4-6	$(mm\phi)$	IXLI.	
L ₁ FM RF	100M	_	ı	100	_	_		2 1 4		0.5UEW	© 0258-000-021	
L ₂ FM OSC	100M	_		100	_	_	1 3	_	_	0.5UEW	© 0258-000-020	
L ₃ AM OSC	796k	268	_	125	14	86	_	_	_	0.06UEW	© 2157-2239-213A	
T ₁ FM MIX	10.7M	_	75	100	_	_	13	_	2	0.1UEW	© 2153-414-041A	
T ₂ AM MIX	455k		330	100	65	45	110	_	6	0.08UEW	S 4140-1289-311	
T ₃ FM DET	10.7M	_	100	95	_	_	12		_	0.12UEW	© 2153-4095-189	

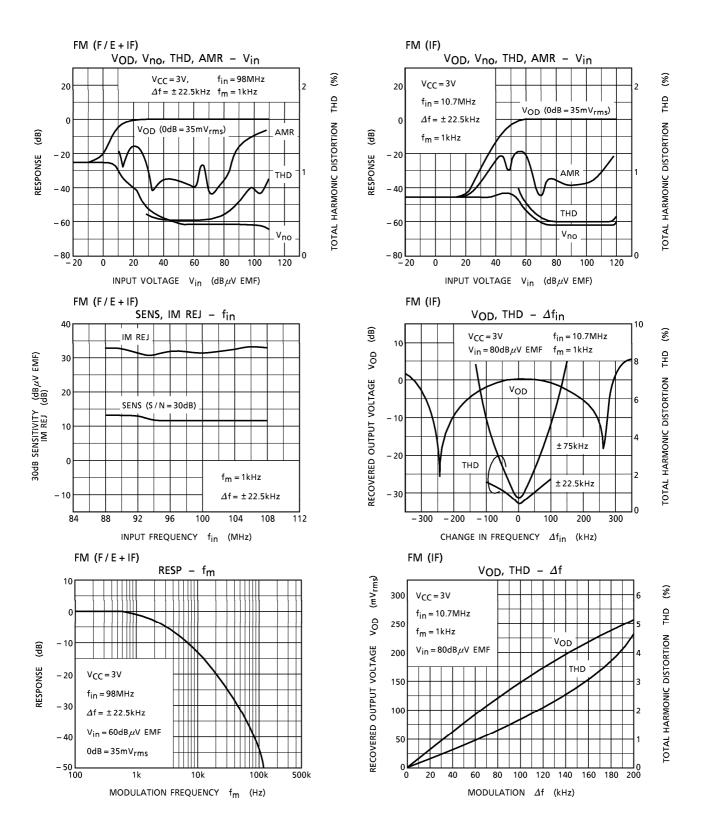
 $\ensuremath{\mathbb{S}}$: SUMIDA ELECTRIC Co., Ltd.

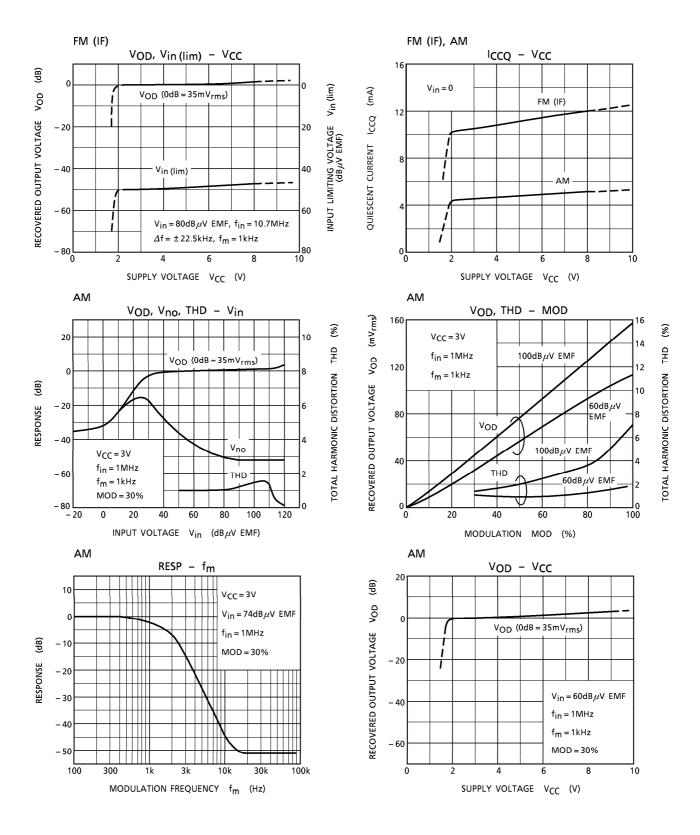






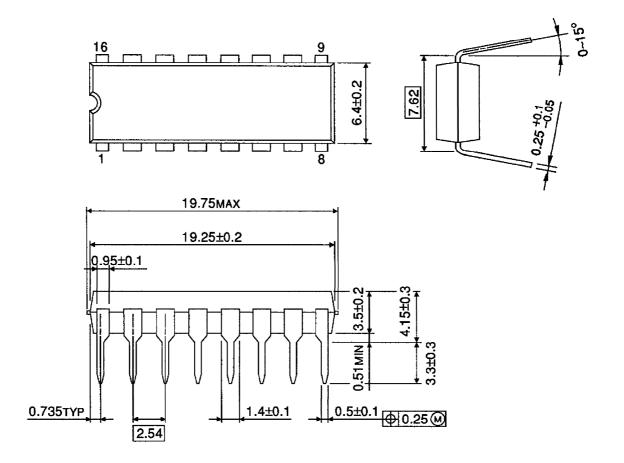






OUTLINE DRAWING DIP16-P-300-2.54A

Unit: mm



Weight: 1.0g (Typ.)

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